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Quad Operational Amplifier



ADE-204-068 (Z)

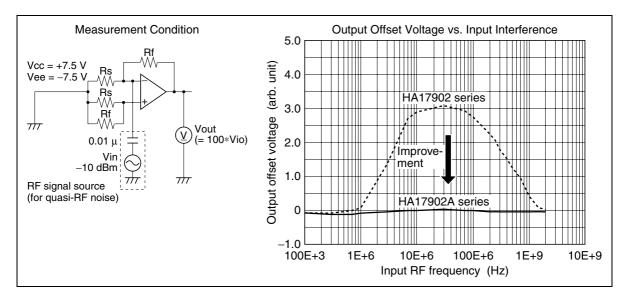
Rev.0 May 2001

Description

HA17902A series are quad operational amplifier that provide high gain and internal phase compensation, with single power supply. They can be widely used to control equipments.

Features

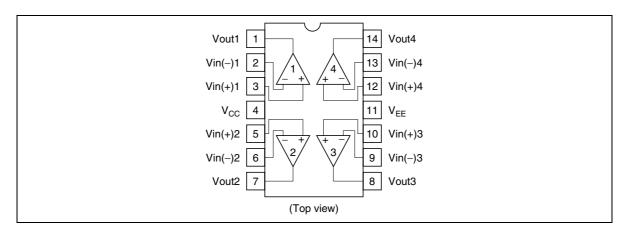
- Wide range of supply voltage, and single power supply used
- Internal phase compensation
- Wide range of common mode voltage, and possible to operate with an input about 0 V
- Low electro-magnetic susceptibility level



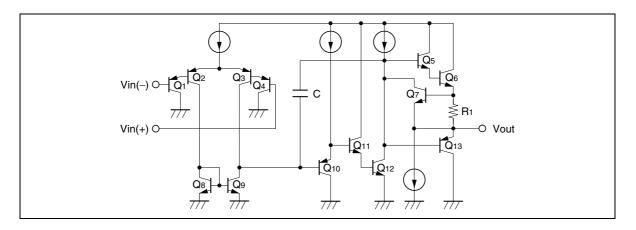
Ordering Information

Type No.	Application	Package
HA17902AP	Industrial use	DP-14
HA17902AFP	_	FP-14DA

Pin Arrangement



Circuit Schematic (1/4)



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Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Supply voltage	V _{cc}	32	V
Sink current	lsink	50	mA
Power dissipation	Ρ _τ	625 * ^{1,2}	mW
Common mode input voltage	V _{CM}	–0.3 to $V_{\rm cc}$	V
Differential input voltage	Vin (diff)	±V _{cc}	V
Operating temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	–55 to +125	°C

Notes: 1. For the DILP package.

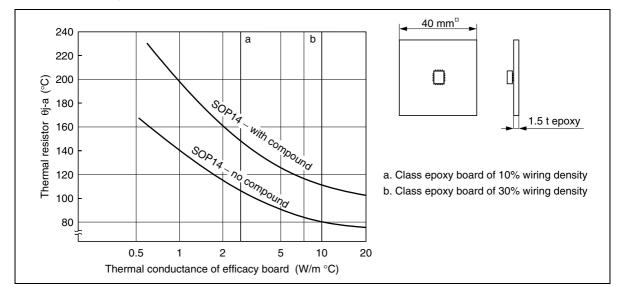
This is the allowable values up to $Ta = 50^{\circ}C$. Derate by 8.3 mW/°C.

2. For the SOP package.

Tjmax = θ j-a · P_cmax + Ta (θ j-a; Thermal resistor between junction and ambient at set board use).

The wiring density and the material of the set board must be chosen for thermal conductance of efficacy board.

And P_c max cannot be over the value of P_{T} .



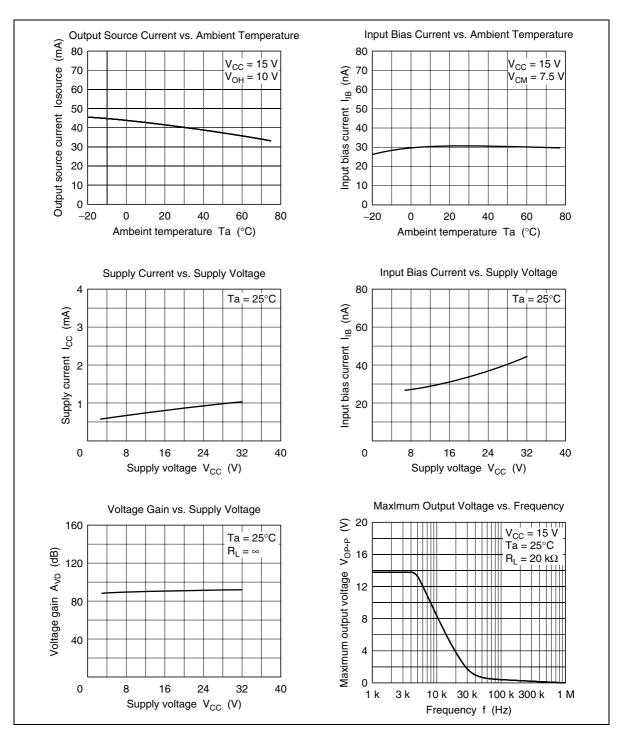
Electrical Characteristics

 $(V_{cc} = +15 \text{ V}, \text{Ta} = 25^{\circ}\text{C})$

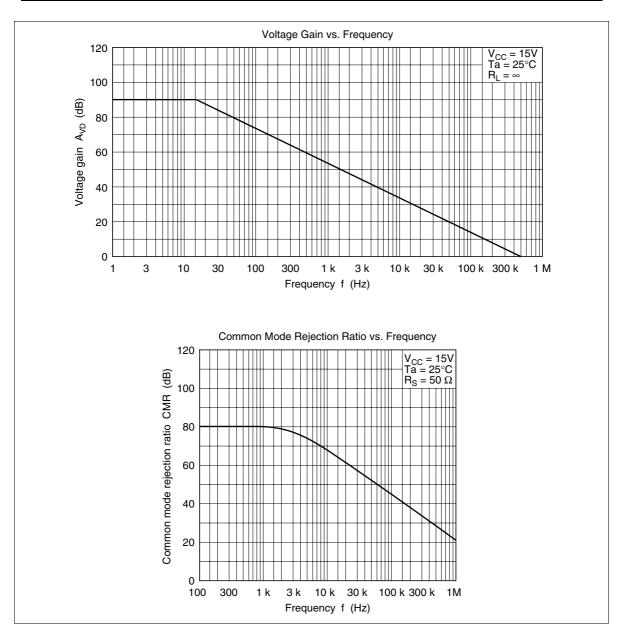
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input offset voltage	V _{IO}		2	7	mV	$V_{_{CM}}$ = 7.5 V, $R_{_{S}}$ = 50 Ω , Rf = 50 k Ω
Input offset current	I _{IO}	—	5	50	nA	$V_{_{CM}} = 7.5 \text{ V}, \text{ I}_{_{IO}} = \text{ I}_{_{I} (-)} - \text{ I}_{_{I} (+)} $
Input bias current	I _{IB}	_	30	500	nA	V _{CM} = 7.5 V
Power source rejection ratio	PSRR	_	93	_	dB	f = 100 Hz, R_s = 1 kΩ, Rj = 100 kΩ
Voltage gain	A_{vD}	75	90	_	dB	$R_{s} = 1 \text{ k}\Omega, \text{ Rf} = 100 \text{ k}\Omega, R_{L} = \infty$
Common mode rejection ratio	CMR	_	80	—	dB	$R_s = 50 \Omega$, $Rf = 5 k\Omega$
Common mode input voltage range	$V_{\rm CM}$	-0.3	_	13.5	V	$R_s = 1 \text{ k}\Omega$, $Rf = 100 \text{ k}\Omega$, $f = 100 \text{ Hz}$
Maximum output voltage	Vор-р	_	13.6	—	V	f = 100 Hz, R_s = 1 kΩ, Rf = 100 kΩ, R_L = 20 kΩ
Output source current	losource	20	40	_	mA	$V_{_{\rm IN}}^{}^{+} = 1 \text{ V}, V_{_{\rm IN}}^{}^{-} = 0 \text{ V}, V_{_{\rm OH}} = 10 \text{ V}$
Output sink current	losink	10	20	_	mA	$V_{_{\rm IN}} = 0 V, V_{_{\rm IN}} = 1 V, V_{_{\rm OL}} = 2.5 V$
Supply current	I _{cc}	_	0.8	2	mA	$V_{_{IN}} = GND, R_{_{L}} = \infty$
Slew rate	SR	_	0.19	_	V/µs	f = 1.5 kHz, $V_{_{CM}}$ = 7.5 V, $R_{_{L}}$ = ∞
Channel separation	CS	_	120	_	dB	f = 1 kHz
Output sink current	losink	15	50	_	μA	$V_{_{\rm IN}}^{^{+}} = 0 \text{ V}, V_{_{\rm IN}}^{^{-}} = 1 \text{ V}, V_{_{\rm OL}} = 200 \text{ mV}$
	losink	3	9	—	mA	$V_{_{\rm IN}}^{^{+}} = 0 \ V, \ V_{_{\rm IN}}^{^{-}} = 1 \ V, \ V_{_{\rm OL}} = 1 \ V$
Output voltage	V _{OH}	13.2	13.6	_	V	I _{он} = -1 mA
	V _{oh}	12.0	13.3	—	V	I _{он} = -10 mA
Output voltage	V _{ol}		0.8	1.0	V	$I_{oL} = 1 \text{ mA}$
	V _{ol}	_	1.1	1.8	V	I _{oL} = 10 mA



Characteristic Curves



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Solder Mounting Method

- Small and light surface-mount packages require spicial attentions on solder mounting. On solder mounting, pre-heating before soldering is needed. The following figure show an example of infrared rays refow.
- 2. The difference of thermal expansion coefficeient between mounted substrates and IC leads may cause a failure like solder peeling or soler wet, and electrical characteristics may change by thermal stress. Therefore, mounting should be done after sufficient confirmation for especially in case of ceramic substrates.

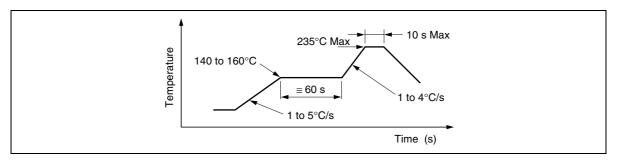
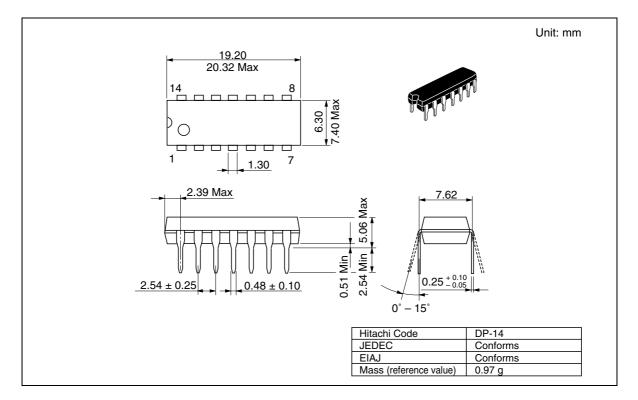
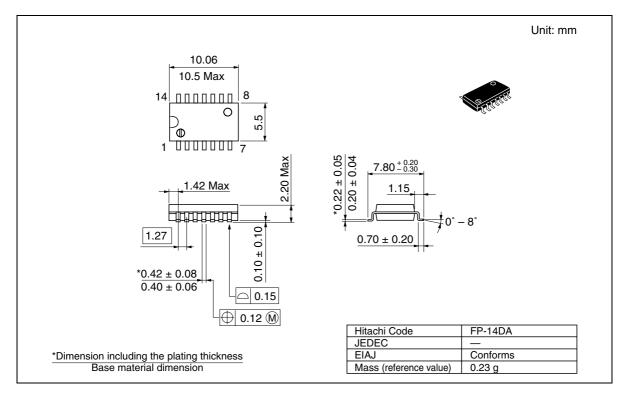


Figure 1 An Example of Infrared Rays Reflow Conditions



Package Dimensions





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